## NSN 5961-01-141-0559

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.240 inches

## **Overall Diameter:**

0.275 inches

#### **End Application:**

F16aircombfit

## Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

## Features Provided:

#### Hermetically sealed case

Thread Size:

0.164 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Precious Material And Location:**

External surfaces gold

#### **Precious Material:**

Gold

## Thread Series Designator:

Unc

## **Terminal Type And Quantity:**

4 ribbon

#### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

